RoHS Compliant

CFast 2H

CFast 2H Product Specifications

July 6, 2015

Version 1.2



Apacer Technology Inc.

1F, No.32, Zhongcheng Rd., Tucheng Dist., New Taipei City, Taiwan, R.O.C Tel: +886-2-2267-8000 Fax: +886-2-2267-2261 www.apacer.com



Features:

- Standard Serial ATA Interface
 - SATA Revision 3.1 compliance
 - SATA 6.0 Gbps interface speed
 - Backward compatible with SATA 1.5 and 3.0 Gbps interfaces
 - ATA-compatible command set
- Connector type
 - 7 + 17 pin female connector
- Power consumption (typical)*
 - Supply voltage: 3.3V
 - Active mode: 540 mA
 - Idle mode: 85 mA
- Performance*
 - Sustained read: Up to 515 MB/sec
 - Sustained write: Up to 145 MB/sec
- Capacity
 - 2, 4, 8, 16, 32, 64 GB
- NAND Flash Type: SLC
- MTBF: >2,000,000 hours

- Temperature ranges
 - Operating: Standard: 0°C to 70°C Wide: -40°C to 85°C
 - Storage: -40°C to 85°C
- Flash Management
 - Built-in hardware ECC
 - Static/dynamic wear-leveling
 - Flash bad-block management
 - S.M.A.R.T.
 - Power Failure Management
 - ATA Secure Erase
 - TRIM
- RoHS Compliant
- DEVSLP Supported

*The values presented in Power consumption and Performances are typical, and may vary depending on different settings and platforms.

1



Table of Contents

1. GENERAL DESCRIPTION	
2. FUNCTIONAL BLOCK	
3. PIN ASSIGNMENTS	
4. PRODUCT SPECIFICATION	6
 4.1 CAPACITY 4.2 PERFORMANCE	6 7 7
5. FLASH MANAGEMENT	
 5.1 ERROR CORRECTION/DETECTION 5.2 BAD BLOCK MANAGEMENT 5.3 WEAR LEVELING 5.4 POWER FAILURE MANAGEMENT 5.5 ATA SECURE ERASE 5.6 S.M.A.R.T 5.7 TRIM 	
6. SOFTWARE INTERFACE	
6.1 ATA COMMAND SET	11
7. ELECTRICAL SPECIFICATION	
7.1 Operating Voltage	
8. PHYSICAL CHARACTERISTICS	
8.1 DIMENSIONS	13
9. PRODUCT ORDERING INFORMATION	



1. General Description

Apacer CFast 2H is the latest enhancement of conventional CFast form factor that delivers various technological advantages. This new flash memory card comes with SATA 6.0 Gbps interface for higher performance and is compliant with standard CFast specifications. CFast 2H consists of SATA-based 7-pin signal segment and 17-pin for power and control purposes. It can offer moderate capacity and decent data transfer performance. For power efficiency, this new flash memory card leverages the technological benefits of SATA Revision 3.0 specifications. For data integrity, the CFast card is built with ECC engine correcting up to 72-bit. Together with its small form factor nature, Apacer CFast 2H is definitely the ideal solution to replace conventional PATA-based CompactFlash for applications in industrial computing systems, mobile computers and video processing instruments.

2. Functional Block

Apacer CFast 2H includes a single-chip SATA 6.0 Gbbps and the flash media. The controller integrates the flash management unit to support multi-channel, multi-bank flash arrays. Figure 2-1 shows the functional block diagram.



Figure 2-1 Apacer CFast block diagram



3. Pin Assignments

Table 3-1 describes CFast 2H signal segment, and Table 3-2, its power segment.



Figure 3-1 Pin Assignment

Pin	Туре	Description
S1	GND	Ground
S2	A+	SATA Differential
S3	A-	Signal Pair A
S4	GND	Ground
S5	В-	SATA Differential
S6	B+	Signal Pair B
S7	GND	Ground

Table 3-1 Signal Segment

Table 3-2 Power Segment

Pin	Definition	Туре	Description	
PC1	CDI	Input	Card Detect In	
PC2	PGND	Device GND	Device GND	
PC3			Reserved	
PC4			Reserved	
PC5			Reserved	
PC6			Reserved	
PC7	PGND	Device GND	Device GND	
PC8	LED1	LED Output	LED Output	
PC9	LED2	LED Output	LED Output	
PC10			Reserved	
PC11			Reserved	
PC12	IFDet	GND	Card output, connect to PGND on card	
PC13	PWR	3.3V	Device power (3.3V)	
PC14	PWR	3.3V	Device power (3.3V)	
PC15	PGND	Device GND	Device GND	
PC16	PGND	Device GND	Device GND	
PC17	CDO	Output	Card Detect Out	





Figure 3-2 SATA Cable / Connector Connection Diagram

The connector on the left represents the Host with TX/RX differential pairs connected to a cable while the connector on the right shows the Device with TX/RX differential pairs also connected to the cable. Notice also the ground path connecting the shielding of the cable to the Cable Receptacle.



4. Product Specification

4.1 Capacity

Capacity specification of the CFast 2H is available as shown in Table 4-1. It lists the specific capacity and the default numbers of heads, sectors and cylinders for each product line.

Capacity	Total bytes*	Cylinders	Heads	Sectors	Max LBA
2 GB	2,011,226,112	3,897	16	63	3,928,176
4 GB	4,011,614,208	7,773	16	63	7,835,184
8 GB	8,012,390,400	15,525	16	63	15,649,200
16 GB	16,013,942,784	16,383	16	63	31,277,232
32 GB	32,017,047,552	16,383	16	63	62,533,296
64 GB	64,023,257,088	16,383	16	63	125,045,424

Table 4-1: Capacity specification

*Display of total bytes varies from file systems.

**Cylinders, heads or sectors are not applicable for these capacities. Only LBA addressing applies

LBA count addressed in the table above indicates total user storage capacity and will remain the same throughout the lifespan of the device. However, the total usable capacity of the CFast is most likely to be less than the total physical capacity because a small portion of the capacity is reserved for device maintenance usages.

4.2 Performance

Performance of CFast 2H product family is available as shown in Table 4-2.

Table 4-2: Performance table

Capacity Performance	2 GB	4 GB	8 GB	16 GB	32 GB	64 GB
Sustained Read (MB/s)	65	65	280	510	495	515
Sustained Write (MB/s)	35	50	80	140	140	145

Note: Performances results are measured by CrystalDiskMark under Windows 7 and may vary from host system configurations.



4.3 Environmental Specifications

Environmental specification of the CFast 2H follows the MIL-STD-810F testing standards, shown in Table 4-3.

Environment		Specification		
		0°C to 70°C / -40°C to 85°C		
Temperature	Storage	-40°C to 85°C		
	Operation	40°C 93%RH		
Humidity	Storage	40°C 95%RH		
Vibration (Non-Operating)		80~2000Hz/20G (acceleration) ; 20~80Hz/1.52mn (displacement), X,Y, Z axis/30 min for each		
Shock (Non-Operating)		Half sine wave, 1500 G (X, Y, Z ; All 6 axis)		
Drop (non-operating)		110cm free fall, 6-face each unit		
Bending (non-operating)		≥20N, hold 1min/5times		
Torque (non-operating)		0.5N-m or ±2.5 degree, hold 5min/5times		

Table 4-3 Environmental specification

Note: this Environmental Specification table indicates the conditions for testing the device. Real world usages may affect the results.

4.4 Mean Time Between Failures (MTBF)

Mean Time Between Failures (MTBF) is predicted based on reliability data for the individual components in CFast 2H. Serving as statistical reference, the prediction result for CFast 2H is more than 2,000,000 hours.

4.5 Certification and Compliance

CFast 2H complies with the following standards

- CE
- FCC
- BSMI
- RoHS



5. Flash Management

5.1 Error Correction/Detection

Flash memory cells will deteriorate with use, which might generate random bit errors in the stored data. Thus, the CFast applies the BCH ECC Algorithm, which can detect and correct errors up to 72-bit in 1K byte data during Read process, ensure data been read correctly, as well as protect data from corruption.

5.2 Bad Block Management

Bad blocks are blocks that include one or more invalid bits, and their reliability is not guaranteed. Blocks that are identified and marked as bad by the manufacturer are referred to as "Initial Bad Blocks". Bad blocks that are developed during the lifespan of the flash are named "Later Bad Blocks". Apacer implements an efficient bad block management algorithm to detect the factory-produced bad blocks and manages any bad blocks that appear with use. This practice further prevents data being stored into bad blocks and improves the data reliability.

5.3 Wear Leveling

NAND Flash devices can only undergo a limited number of program/erase cycles, and in most cases, the flash media are not used evenly. If some areas get updated more frequently than others, the lifetime of the device would be reduced significantly. Thus, Wear Leveling technique is applied to extend the lifespan of NAND Flash by evenly distributing write and erase cycles across the media.

Apacer provides advanced Wear Leveling algorithm, which can efficiently spread out the flash usage through the whole flash media area. Moreover, by implementing both dynamic and static Wear Leveling algorithms, the life expectancy of the NAND Flash is greatly improved.

5.4 Power Failure Management

Power Failure Management is a mechanism to prevent data loss during unexpected power failure. When power outage occurs, the data that has not been written into NAND Flash is in risk. Thus, the purpose of this mechanism is to request the controller to transfer data to the cache. In this CFast 2H structure, SDR performs as a cache, and its sizes is 32MB. Only when the data is fully committed to the NAND flash will the controller send acknowledgement (ACK) to the host. Such implementation can prevent false-positive performance and the risk of power cycling issues.

Additionally, it is critical for a controller to shorten the time the in-flight data stays in the cache. Thus, this CFast 2H memory card applies an algorithm to reduce the amount of data resides in the cache to provide a better performance. This allows incoming data to only have a "pit stop" in the cache and then move to the NAND flash at once. If the flash is jammed due to particular file sizes (random 4K), the cache will be treated as an "organizer", consolidating incoming data into groups before written into the flash to improve write amplification.



5.5 ATA Secure Erase

ATA Secure Erase is an ATA disk purging command currently embedded in most of the storage drives. Defined in ATA specifications, (ATA) Secure Erase is part of Security Feature Set that allows storage drives to erase all user data areas. The erase process usually runs on the firmware level as most of the ATA-based storage media currently in the market are built-in with this command. ATA Secure Erase can securely wipe out the user data in the drive and protects it from malicious attack.

5.6 S.M.A.R.T.

SMART, an acronym for Self-Monitoring, Analysis and Reporting Technology, is an open standard that allows a hard disk drive to automatically detect its health and report potential failures. When a failure is recorded by SMART, users can choose to replace the drive to prevent unexpected outage or data loss. Moreover, SMART can inform users of impending failures while there is still time to perform proactive actions, such as copy data to another device.

Apacer devices use the standard SMART command B0h to read data out from the drive to activate our S.M.A.R.T. feature that complies with the ATA/ATAPI specifications. S.M.A.R.T. Attribute IDs shall include initial bad block count, total later bad block count, maximum erase count, average erase count, power on hours and power cycle. When the S.M.A.R.T. Utility running on the host, it analyzes and reports the disk status to the host before the device reaches in critical condition.

Note: attribute IDs may vary from product models due to various solution design and supporting capabilities.

Apacer memory products come with S.M.A.R.T. commands and subcommands for users to obtain information of drive status and to predict potential drive failures. Users can take advantage of the following commands/subcommands to monitor the health of the drive.

CODE	SMART SUBCOMMAND
D0H	READ DATA
D1H	READ ATTRIBUTE THRESHOLDS
D2H	ENABLE/DISABLE ATTRIBUTE AUTOSAVE
D4H	EXECUTE OFF-LINE IMMEDIATE
D5H	READ LOG (OPTIONAL)
D6H	WRITE LOG (OPTIONAL)
D8H	ENABLE OPERATIONS
D9H	DISABLE OPERATIONS
Dah	RETURN STATUS

	GENERAL OMART ATTRIBUTE STRUCTURE			
BYTE	BYTE DESCRIPTION			
0	ID (HEX)			
1-2	STATUS FLAG			
3	VALUE			
4	WORST			
5*-11	RAW DATA			

GENERAL SMART ATTRIBUTE STRUCTURE

*Byte 5: LSB



SMART attribute ID list

ID (HEX)	ATTRIBUTE NAME
9 (0x09)	POWER-ON HOURS
12 (0x0C)	POWER CYCLE COUNT
163 (0xA3)	MAX. ERASE COUNT
164 (0xA4)	AVG. ERASE COUNT
166 (0xA6)	TOTAL LATER BAD BLOCK COUNT
167 (0xA7)	SSD PROTECT MODE (VENDOR SPECIFIC)
168 (0xA8)	SATA PHY ERROR COUNT
175 (0xAF)	BAD CLUSTER TABLE COUNT
192 (0xC0)	UNEXPECTED POWER LOSS COUNT
194 (0xC2)	TEMPERATURE
241 (0xF1)	TOTAL SECTORS OF WRITE

5.7 TRIM

TRIM is a feature which helps improve the read/write performance and speed of Solid-State Drives (SSD). Unlike Hard Disk Drives (HDD), SSDs are not able to overwrite existing data, so the available space gradually becomes smaller with each use. With the TRIM command, the operating system can inform the SSD which blocks of data are no longer in use and can be removed permanently. Thus, the SSD will perform the erase action, which prevents unused data from occupying blocks all the time.



6. Software Interface

6.1 ATA Command Set

Code Command Code Command 06h Data Set Management 98h Check Power Mode 10h-1Fh Recalibrate 99h Sleep 20h Read Sectors B0h SMART 21h Read Sectors without Retry B1h Device Configuration 24h Read Sectors EXT C4h Read Multiple 25h Read DMA EXT C5h Write Multiple 27h Read Native Max Address EXT C6h Set Multiple Mode 29h Read Multiple EXT C8h Read DMA 2Fh Read Log EXT C9h Read DMA 30h Write Sectors Cah Write DMA 31h Write Sectors inthout Retry CBh Write Multiple FUA EXT 34h Write Sectors EXT Ceh Write Multiple FUA EXT 35h Write DMA EXT E0h Standby immediate 37h Set Native Max Address EXT E1h Idle 38h CFA Write Sectors without Erase E2h Standby <t< th=""><th></th><th colspan="7"></th></t<>								
10h-1Fh Read Sectors B0h SMART 21h Read Sectors without Retry B1h Device Configuration 24h Read Sectors EXT C4h Read Multiple 25h Read DMA EXT C5h Write Multiple 27h Read Native Max Address EXT C6h Set Multiple Mode 29h Read Multiple EXT C6h Read DMA 29h Read Log EXT C9h Read DMA 30h Write Sectors Cah Write DMA 31h Write Sectors without Retry CBh Write DMA 31h Write Sectors EXT Ceh Write DMA 33h Write Sectors without Retry CBh Standby immediate 37h Set Native Max Address EXT E1h Idle 38h CFA Write Sectors without Erase E2h Standby 39h Write Mutiple EXT E3h Idle 30h Write Mutiple EXT E3h Idle 39h Write Max Address EXT E1h Idle 39h Write Max Address EXT E1h Idle 39h Write Sectors without Erase E2h Standby 39h Write Max Address EXT E3h Idle 30h	Code	Command	Code	Command				
20hRead SectorsB0hSMART21hRead Sectors without RetryB1hDevice Configuration24hRead Sectors EXTC4hRead Multiple25hRead DMA EXTC5hWrite Multiple27hRead Native Max Address EXTC6hSet Multiple Mode29hRead Multiple EXTC8hRead DMA2FhRead Log EXTC9hRead DMA without Retry30hWrite SectorsCahWrite DMA31hWrite Sectors without RetryCBhWrite Multiple FUA EXT34hWrite Sectors EXTCehWrite Multiple FUA EXT35hWrite DMA EXTE0hStandby immediate37hSet Native Max Address EXTE1hIdle38hCFA Write Sectors without EraseE2hStandby39hWrite IMA EXTE3hIdle30hWrite Mark EXTE3hIdle39hWrite Max EXTE4hRead Buffer39hWrite Mark SectorsE6hSleep41hRead Verify SectorsE6hSleep41hRead Verify Sectors EXTEahFlush Cache42hRead Verify Sectors EXTEahFlush Cache EXT60hRead PDMA QueuedEchIdentify Device61hWrite Incorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEchIdentify Device61hWrite FPDMA QueuedEfhSecurity Set Password90hExecute Device DiagonsticF2hS	06h	Data Set Management	98h	Check Power Mode				
21hRead Sectors without RetryB1hDevice Configuration24hRead Sectors EXTC4hRead Multiple25hRead DMA EXTC5hWrite Multiple27hRead Native Max Address EXTC6hSet Multiple Mode29hRead Multiple EXTC8hRead DMA2FhRead Log EXTC9hRead DMA30hWrite SectorsCahWrite DMA31hWrite Sectors without RetryCBhWrite DMA without Retry34hWrite Sectors EXTCehWrite Multiple FUA EXT35hWrite DMA EXTE0hStandby immediate37hSet Native Max Address EXTE1hIdle Immediate38hCFA Write Sectors without EraseE2hStandby39hWrite Multiple EXTE3hIdle30hWrite DMA FUA EXTE4hRead Buffer37hSet Nuite Sectors without RetryE7hCheck Power Mode39hWrite IDMA FUA EXTE5hCheck Power Mode40hRead Verify SectorsE6hSleep41hRead Verify SectorsE6hSleep41hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache42hRead PDMA QueuedEfhSecurity Set Password60hRead FPDMA QueuedEfhSecurity Erase Prepare70h-7FhSeekF1hSecurity Erase Prepare90hExecute Device DiagonsticF2hSecurity Erase Unit <td< td=""><td>10h-1Fh</td><td>Recalibrate</td><td>99h</td><td>Sleep</td></td<>	10h-1Fh	Recalibrate	99h	Sleep				
24hRead Sectors EXTC4hRead Multiple25hRead DMA EXTC5hWrite Multiple27hRead Native Max Address EXTC6hSet Multiple Mode29hRead Multiple EXTC8hRead DMA2FhRead Log EXTC9hRead DMA without Retry30hWrite SectorsCahWrite DMA31hWrite Sectors without RetryCBhWrite DMA without Retry34hWrite Sectors EXTCehWrite Multiple FUA EXT35hWrite DMA EXTE0hStandby immediate37hSet Native Max Address EXTE1hIdle38hCFA Write Sectors without EraseE2hStandby39hWrite IMA FUA EXTE3hIdle30hWrite IDMA EXTE3hIdle30hWrite IDMA EXTE3hIdle30hRead Verify SectorsE6hSleep41hRead Verify Sectors EXTE8hWrite Buffer4	20h	Read Sectors	B0h	SMART				
25hRead DMA EXTC5hWrite Multiple27hRead Native Max Address EXTC6hSet Multiple Mode29hRead Multiple EXTC8hRead DMA2FhRead Log EXTC9hRead DMA without Retry30hWrite SectorsCahWrite DMA31hWrite Sectors without RetryCBhWrite DMA without Retry34hWrite Sectors EXTCehWrite Multiple FUA EXT35hWrite DMA EXTE0hStandby immediate37hSet Native Max Address EXTE1hIdle Immediate38hCFA Write Sectors without EraseE2hStandby39hWrite Multiple EXTE3hIdle3DhWrite DMA FUA EXTE4hRead Buffer3FhWrite Iong EXTE5hCheck Power Mode40hRead Verify SectorsE6hSleep41hRead Verify Sectors EXTE3hWrite Buffer42hRead Verify Sectors EXTE3hWrite Buffer45hWrite Uncorrectable EXTE3hWrite Buffer45hWrite Uncorrectable EXTE3hFlush Cache EXT60hRead FPDMA QueuedEfhSecurity Set Password90hExecute Device DiagonsticF2hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Freeze Lock93hIdle ImmediateF6hSecurity Disable Password93hIdle ImmediateF6hSecurit	21h	Read Sectors without Retry	B1h	Device Configuration				
27hRead Native Max Address EXTC6hSet Multiple Mode29hRead Multiple EXTC8hRead DMA2FhRead Log EXTC9hRead DMA without Retry30hWrite SectorsCahWrite DMA31hWrite Sectors without RetryCBhWrite DMA without Retry34hWrite Sectors EXTCehWrite DMA without Retry35hWrite DMA EXTE0hStandby immediate37hSet Native Max Address EXTE1hIdle Immediate38hCFA Write Sectors without EraseE2hStandby39hWrite Multiple EXTE3hIdle30hWrite DMA FUA EXTE4hRead Buffer37hSet Native Max AddressE5hCheck Power Mode39hWrite Multiple EXTE3hIdle30hWrite DMA FUA EXTE4hRead Buffer37hWrite Iong EXTE5hCheck Power Mode30hRead Verify SectorsE6hSleep40hRead Verify Sectors EXTE7hFlush Cache41hRead Verify Sectors EXTE8hWrite Buffer42hRead Verify Sectors EXTE8hVirite Buffer45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEchIdentify Device61hWrite FPDMA QueuedEfhSecurity Set Password90hExecute Device DiagonsticF2hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Freeze Lock	24h	Read Sectors EXT	C4h	Read Multiple				
29hRead Multiple EXTC8hRead DMA2FhRead Log EXTC9hRead DMA without Retry30hWrite SectorsCahWrite DMA31hWrite Sectors without RetryCBhWrite DMA without Retry34hWrite Sectors EXTCehWrite Multiple FUA EXT35hWrite DMA EXTE0hStandby immediate37hSet Native Max Address EXTE1hIdle Immediate38hCFA Write Sectors without EraseE2hStandby39hWrite Multiple EXTE3hIdle3DhWrite DMA FUA EXTE4hRead Buffer3FhWrite Long EXTE5hCheck Power Mode40hRead Verify SectorsE6hSleep41hRead Verify Sectors without RetryE7hFlush Cache42hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache45hWrite Uncorrectable EXTEahFlush Cache45hWrite FPDMA QueuedEthSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Frease Unit93hDownload MicrocodeF4hSecurity Frease Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	25h	Read DMA EXT	C5h	Write Multiple				
2FhRead Log EXTC9hRead DMA without Retry30hWrite SectorsCahWrite DMA31hWrite Sectors without RetryCBhWrite DMA without Retry34hWrite Sectors EXTCehWrite Multiple FUA EXT35hWrite DMA EXTE0hStandby immediate37hSet Native Max Address EXTE1hIdle Immediate38hCFA Write Sectors without EraseE2hStandby39hWrite Multiple EXTE3hIdle30hWrite DMA FUA EXTE4hRead Buffer37hWrite Induction EXTE5hCheck Power Mode39hWrite Long EXTE5hCheck Power Mode40hRead Verify SectorsE6hSleep41hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Freeze Lock93hDownload Microcode DMAF5hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	27h	Read Native Max Address EXT	C6h	Set Multiple Mode				
30hWrite SectorsCahWrite DMA31hWrite Sectors without RetryCBhWrite DMA without Retry34hWrite Sectors EXTCehWrite Multiple FUA EXT35hWrite DMA EXTE0hStandby immediate37hSet Native Max Address EXTE1hIdle Immediate38hCFA Write Sectors without EraseE2hStandby39hWrite Multiple EXTE3hIdle3DhWrite DMA FUA EXTE4hRead Buffer3FhWrite Long EXTE5hCheck Power Mode40hRead Verify SectorsE6hSleep41hRead Verify Sectors without RetryE7hFlush Cache42hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEchIdentify Device61hWrite FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Case Prepare92hDownload MicrocodeF4hSecurity Erase Prepare92hDownload Microcode DMAF5hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	29h	Read Multiple EXT	C8h	Read DMA				
31hWrite Sectors without RetryCBhWrite DMA without Retry34hWrite Sectors EXTCehWrite Multiple FUA EXT35hWrite DMA EXTE0hStandby immediate37hSet Native Max Address EXTE1hIdle Immediate38hCFA Write Sectors without EraseE2hStandby39hWrite Multiple EXTE3hIdle30hWrite DMA FUA EXTE4hRead Buffer3FhWrite Long EXTE5hCheck Power Mode40hRead Verify SectorsE6hSleep41hRead Verify Sectors without RetryE7hFlush Cache42hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	2Fh	Read Log EXT	C9h	Read DMA without Retry				
34hWrite Sectors EXTCehWrite Multiple FUA EXT35hWrite DMA EXTE0hStandby immediate37hSet Native Max Address EXTE1hIdle Immediate38hCFA Write Sectors without EraseE2hStandby39hWrite Multiple EXTE3hIdle3DhWrite DMA FUA EXTE4hRead Buffer3FhWrite Long EXTE5hCheck Power Mode40hRead Verify SectorsE6hSleep41hRead Verify Sectors without RetryE7hFlush Cache42hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEchIdentify Device61hWrite FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Treeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	30h	Write Sectors	Cah	Write DMA				
35hWrite DMA EXTE0hStandby immediate37hSet Native Max Address EXTE1hIdle Immediate38hCFA Write Sectors without EraseE2hStandby39hWrite Multiple EXTE3hIdle3DhWrite DMA FUA EXTE4hRead Buffer3FhWrite Long EXTE5hCheck Power Mode40hRead Verify SectorsE6hSleep41hRead Verify Sectors without RetryE7hFlush Cache42hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Erase Prepare91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	31h	Write Sectors without Retry	CBh	Write DMA without Retry				
37hSet Native Max Address EXTE1hIdle Immediate38hCFA Write Sectors without EraseE2hStandby39hWrite Multiple EXTE3hIdle3DhWrite DMA FUA EXTE4hRead Buffer3FhWrite Long EXTE5hCheck Power Mode40hRead Verify SectorsE6hSleep41hRead Verify Sectors without RetryE7hFlush Cache42hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEchIdentify Device61hWrite FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	34h	Write Sectors EXT	Ceh	Write Multiple FUA EXT				
38hCFA Write Sectors without EraseE2hStandby39hWrite Multiple EXTE3hIdle3DhWrite DMA FUA EXTE4hRead Buffer3FhWrite Long EXTE5hCheck Power Mode40hRead Verify SectorsE6hSleep41hRead Verify Sectors without RetryE7hFlush Cache42hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEchIdentify Device61hWrite FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	35h	Write DMA EXT	E0h	Standby immediate				
39hWrite Multiple EXTE3hIdle3DhWrite DMA FUA EXTE4hRead Buffer3FhWrite Long EXTE5hCheck Power Mode40hRead Verify SectorsE6hSleep41hRead Verify Sectors without RetryE7hFlush Cache42hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEchIdentify Device61hWrite FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Freeze Lock93hDownload MicrocodeF4hSecurity Disable Password94hStandby ImmediateF8hRead Native Max Address	37h	Set Native Max Address EXT	E1h	Idle Immediate				
3DhWrite DMA FUA EXTE4hRead Buffer3FhWrite Long EXTE5hCheck Power Mode40hRead Verify SectorsE6hSleep41hRead Verify Sectors without RetryE7hFlush Cache42hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEchIdentify Device61hWrite FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	38h	CFA Write Sectors without Erase	E2h	Standby				
3FhWrite Long EXTE5hCheck Power Mode40hRead Verify SectorsE6hSleep41hRead Verify Sectors without RetryE7hFlush Cache42hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEchIdentify Device61hWrite FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	39h	Write Multiple EXT	E3h	Idle				
40hRead Verify SectorsE6hSleep41hRead Verify Sectors without RetryE7hFlush Cache42hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEchIdentify Device61hWrite FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload Microcode DMAF5hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	3Dh	Write DMA FUA EXT	E4h	Read Buffer				
41hRead Verify Sectors without RetryE7hFlush Cache42hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEchIdentify Device61hWrite FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	3Fh	Write Long EXT	E5h	Check Power Mode				
42hRead Verify Sectors EXTE8hWrite Buffer45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEchIdentify Device61hWrite FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	40h	Read Verify Sectors	E6h	Sleep				
45hWrite Uncorrectable EXTEahFlush Cache EXT60hRead FPDMA QueuedEchIdentify Device61hWrite FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Erase Unit93hDownload Microcode DMAF5hSecurity Freeze Lock94hStandby ImmediateF8hRead Native Max Address	41h	Read Verify Sectors without Retry	E7h	Flush Cache				
60hRead FPDMA QueuedEchIdentify Device61hWrite FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Erase Unit93hDownload Microcode DMAF5hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	42h	Read Verify Sectors EXT	E8h	Write Buffer				
61hWrite FPDMA QueuedEfhSet Features70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Erase Unit93hDownload Microcode DMAF5hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	45h	Write Uncorrectable EXT	Eah	Flush Cache EXT				
70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Erase Unit93hDownload Microcode DMAF5hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	60h	Read FPDMA Queued	Ech	Identify Device				
70h-7FhSeekF1hSecurity Set Password90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Erase Unit93hDownload Microcode DMAF5hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	61h	Write FPDMA Queued	Efh	Set Features				
90hExecute Device DiagonsticF2hSecurity Unlock91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Erase Unit93hDownload Microcode DMAF5hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address		Seek	F1h	Security Set Password				
91hInitialize Device ParametersF3hSecurity Erase Prepare92hDownload MicrocodeF4hSecurity Erase Unit93hDownload Microcode DMAF5hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address	90h	Execute Device Diagonstic	F2h					
92hDownload MicrocodeF4hSecurity Erase Unit93hDownload Microcode DMAF5hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address								
93hDownload Microcode DMAF5hSecurity Freeze Lock94hStandby ImmediateF6hSecurity Disable Password95hIdle ImmediateF8hRead Native Max Address				Security Erase Unit				
94h Standby Immediate F6h Security Disable Password 95h Idle Immediate F8h Read Native Max Address								
95h Idle Immediate F8h Read Native Max Address								
97h Idle								

Table 6-1: Command set



7. Electrical Specification

7.1 Operating Voltage

Table 7-1 lists operating voltage of CFast 2H

Table 7-1: Operating voltage	Table 7	-1: Ope	erating	voltage
------------------------------	---------	---------	---------	---------

Parameter	Symbol	Min	Тур	Мах	Units
Power Supply	Vcc	3.135	3.3	3.465	V

7.2 Power Consumption

Table 7-2 lists power consumption of CFast 2H

Table 7-2 Power co	onsumption (typical)
--------------------	----------------------

Capacity Mode	2 GB	4 GB	8 GB	16 GB	32 GB	64 GB
Active (mA)	210	225	340	500	515	540
Standby (mA)	65	65	85	85	85	85

Note: Power consumption may vary from flash configurations and/or platform settings.



8. Physical Characteristics

8.1 Dimensions



FIGURE 8-1: Physical dimension



9. Product Ordering Information

9.1 Product Code Designations





9.2 Valid Combinations

9.2.1 Standard Temperature

Capacity	AP/N
2GB	APCFA002GBAN-DT
4GB	APCFA004GBAN-DT
8GB	APCFA008GBAD-DT
16GB	APCFA016GBAD-DT
32GB	APCFA032GBAD-DT
64GB	APCFA064GBAD-DT

9.2.2 Wide Temperature

Capacity	AP/N
2GB	APCFA002GBAN-WDT
4GB	APCFA004GBAN-WDT
8GB	APCFA008GBAD-WDT
16GB	APCFA016GBAD-WDT
32GB	APCFA032GBAD-WDT
64GB	APCFA064GBAD-WDT



Revision History

Revision	Date	Description	Remark
1.0	11/28/2014	Official Released	
1.1	12/03/2014	Revised 5.6 SMART section	
1.2	07/06/2015	Revised product ordering information	



Global Presence

Taiwan (Headquarters)	Apacer Technology Inc. 1F., No.32, Zhongcheng Rd., Tucheng Dist., New Taipei City 236, Taiwan R.O.C. Tel: 886-2-2267-8000 Fax: 886-2-2267-2261 amtsales@apacer.com
U.S.A.	Apacer Memory America, Inc. 386 Fairview Way, Suite102, Milpitas, CA 95035 Tel: 1-408-518-8699 Fax: 1-408-935-9611 <u>sa@apacerus.com</u>
Japan	Apacer Technology Corp. 5F, Matsura Bldg., Shiba, Minato-Ku Tokyo, 105-0014, Japan Tel: 81-3-5419-2668 Fax: 81-3-5419-0018 jpservices@apacer.com
Europe	Apacer Technology B.V. Science Park Eindhoven 5051 5692 EB Son, The Netherlands Tel: 31-40-267-0000 Fax: 31-40-267-0000#6199 sales@apacer.nl
China	Apacer Electronic (Shanghai) Co., Ltd 1301, No.251,Xiaomuqiao Road, Shanghai, 200032, China Tel: 86-21-5529-0222 Fax: 86-21-5206-6939 sales@apacer.com.cn
India	Apacer Technologies Pvt Ltd, # 535, 1st Floor, 8th cross, JP Nagar 3rd Phase, Bangalore – 560078, India Tel: 91-80-4152-9061 sales_india@apacer.com